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## Article

# Comparison of Brillouin Light Scattering and Density of States in a Supported Layer: Analytical and Experimental Study

Ossama El Abouti <sup>1</sup>, John Cuffe <sup>2,3</sup>, El Houssaine El Boudouti <sup>4,\*</sup> , Clivia M. Sotomayor Torres <sup>2,5</sup> ,  
Emigdio Chavez-Angel <sup>2</sup> , Bahram Djafari-Rouhani <sup>6</sup>  and Francesc Alzina <sup>2</sup> 

<sup>1</sup> Faculté des Sciences et Techniques, Al Hoceima, Université Abdelmalek Essadi, Tétouan 93000, Morocco

<sup>2</sup> Catalan Institute of Nanoscience and Nanotechnology (ICN2), CSIC and BIST, Campus UAB, Bellaterra, 08193 Barcelona, Spain

<sup>3</sup> Department of Physics, University College Cork, College Road, T12 K8AF Cork, Ireland

<sup>4</sup> LPMR, Département de Physique, Faculté des Sciences, Université Mohammed I, Oujda 60000, Morocco

<sup>5</sup> ICREA, Pg. Lluís Companys 23, 08010 Barcelona, Spain

<sup>6</sup> Département de Physique, IEMN, Université de Lille, 59655 Lille, France

\* Correspondence: e.elboudouti@ump.ac.ma

**Abstract:** We provide a detailed analytical calculation of the Brillouin light scattering (BLS) intensity of a layer on a substrate, taking into account both photoelastic and moving boundary (ripple effect) mechanisms, and give a comparison between BLS intensity and density of states (DOS) to determine the dispersion curves of longitudinal guided modes in the supported layer. In particular, in the case where the mismatch between the elastic parameters of the substrate and the adsorbed layer is high, such as in a PMMA layer on a Si substrate, we derive closed-form expressions of BLS and DOS and demonstrate a simple relationship between these two quantities. A very good agreement between experimental and theoretical BLS spectra was found and compared to theoretical DOS spectra. In particular, we show that while the peaks in the DOS present a uniform behavior, the BLS spectra follows a sine cardinal (sinc) function shape around a given frequency fixed by the chosen laser wavelength. The theoretical calculation is performed within the framework of the Green's function approach.

**Keywords:** Brillouin light scattering; density of states; supported layer; Green's function



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## 1. Introduction

Physical properties of thin supported layers are of specific interest, as they are often different from those of bulk materials, mainly the transport properties [1]. These properties are of fundamental importance for the development of high-performance devices. The propagation of surface acoustic waves in supported layers has been extensively studied [1–13]. On the other hand, the so-called longitudinal guided modes have also attracted significant attention [14–19]. Experimental evidence of the existence of these modes has been obtained for one supported layer deposited on a substrate such as Mo/Si [6], Si (amorphous)/Si(crystalline) [7], SiO<sub>2</sub>/GaAs [8], ZnSe/GaAs [14], WC/Si [10] and recently in heterostructure semiconductor/topological insulator Si/Bi<sub>2</sub>Te<sub>3</sub> [13]. Generation of modes in more complicated structures such as interconnected Al stripes and pillars deposited on a Si substrate has been reported [20].

In this regard, polymer layers are attractive model systems to investigate phonon confinement due to their elasticity, transparency and inexpensive fabrication in contrast to rigid layers. The acoustic properties of supported polymer layers are of key importance in advancing Nanoimprint Lithography and other polymer-coating-based technologies [21]. As well as being a convenient system for the study of phonon confinement, the acoustic properties of nanoscale layers of polymers are important for the fabrication of nanostructures, for a range of applications including micro/nano-electronics, nanophotonics and nanofluidics. An example of a study on the acoustic properties of polymer layers, ranging

in thickness from 40 nm to 3  $\mu\text{m}$ , was performed by Gomopoulos et al. [22,23]. By employing BLS, they measured the longitudinal modulus in supported thin polymer films in the direction normal to the film surface.

Furthermore, the manipulation of elastic wave propagation given by combining materials of significantly different acoustic impedance in a periodic structure has been investigated both experimentally and theoretically [24–30]. Potential applications of these periodic structures include the enhancement of interaction between acoustic and visible light waves, which can enable coherent phonon generation [31–34], concurrent modulation of light and sound [35–37], acoustic diodes [38] and sensors [39,40]. Recently, the study of hybrid superlattices consisting of alternating silica and poly(methylmethacrylate) ( $\text{SiO}_2$ -PMMA) studied by non-destructive BLS has advanced our knowledge of phononic wave propagation [41–43]. The large mismatch between the physical properties of polymer layers is the key parameter in determining the phononic properties of these periodic nanocomposites, as the width of the phonon band gaps depends on the difference between the acoustic impedances of the constituents. More recently, the direction-dependent elastic and electromagnetic wave propagation has been studied by some of us experimentally and theoretically in supported films of PMMA- $\text{TiO}_2$  [44] and PMMA- $\text{BaTiO}_3$  [45] multilayers with a periodicity of about 100–140 nm. In these studies, full theoretical description of the phononic density of states (DOS) recorded by BLS was derived.

Another method that enables revealing the surface acoustic waves' existence in multilayers is the so-called picosecond ultrasonics based on the ultrafast pump–probe technique [46]. Recently, this method has been used to generate and detect surface acoustic waves on a structure consisting of nanoscale Al lines on a  $\text{SiO}_2$  layer deposited on Si substrate [47] and to probe the mechanical properties of single vegetal cells [48].

Among different mathematical approaches, the Green's function formalism [1,28] is particularly convenient for studying the spectral properties of these types of excitations; in particular, it enables the calculation of the total or local DOS in which the resonant (leaky) modes appear as well-defined peaks. Let us recall that the vibrational DOS is often used for the integrated function over the phonon wavevector  $q$  in condensed matter physics such as the heat capacity and thermal conductivity [49]. Several works have reported the extraction of the DOS from measurable quantities such as: the nuclear resonant scattering to derive the phonon DOS [50], the differential conductance in scanning tunneling spectroscopy to obtain electron charge density [51] and the conductivity correction in semiconductors to deduce the Fermi energy [52]. Additionally, several works have used the DOS spectra to analyze the different modes obtained from the experimental BLS measurements in layered media [10,14,43,53–55]. In the case of oblique incidence (in-plane propagation) and for an opaque layer, the scattering occurs at the free surface of the layer and it was shown that the BLS spectra is proportional to the local DOS evaluated at the surface [10,28]. For a normal incidence (out-of-plane propagation), it was shown that the experimental BLS spectra follows a sine cardinal (sinc) function [14,22,23,55,56]. However, to our knowledge, there is no analytical comparison between the total DOS and the BLS spectra in the latter case.

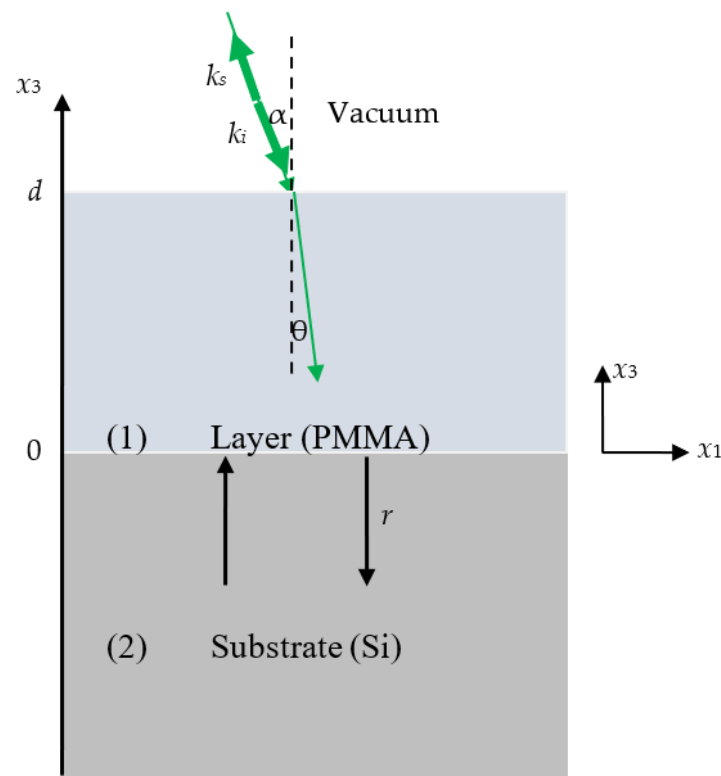
In this work we give an analytical and experimental demonstration of the comparison between BLS and DOS to determine the dispersion curves of pure longitudinal acoustic modes propagating perpendicular to a thin layer deposited on the substrate. In the case where the mismatch between the elastic parameters of the substrate and the adsorbed layer is high such as PMMA layer on Si substrate, we obtain closed-form expressions of BLS and DOS and demonstrate a simple relationship between these two quantities. A very good agreement between experimental and theoretical BLS spectra is found and compared to theoretical DOS spectra. In particular, we show that while the peaks in the DOS present a uniform behavior, the BLS spectra follow a sinc function shape around a given frequency fixed by the chosen laser wavelength. Another result of the paper is an exact relationship between DOS and the delay time of the reflection coefficient which can be measured in an acoustic experiment.

This paper is organized as follows: in Section 2 we present the analytical calculations of the BLS intensity and DOS. These calculations are obtained using the Green's function method [28]. Section 3 presents the experimental and numerical results concerning the BLS and DOS spectra of PMMA layer deposited on Si substrate. Section 4 summarizes the principal results of this work.

## 2. Analytical Results

### 2.1. Scattering Intensity in a Supported Layer

We consider (Figure 1) a structure formed out of one adsorbed layer (labeled  $i = 1$ ) of thickness  $d$  deposited on a homogeneous substrate (labeled  $i = 2$ ) along the  $x_3$  axis. All the interfaces are taken to be parallel to the  $x_1 - x_2$  plane. At normal incidence and for isotropic media, there is a decoupling between longitudinal and transverse waves in the media and the former can be treated separately. Each medium within the stack is defined by its mass density  $\rho_i$ , its optical index  $n_i$ , longitudinal sound velocity  $v_i$ , and photoelastic constant  $p_i$ . The corresponding elastic constants and acoustic impedances are given by  $C_{11}^i = \rho_i v_i^2$  and  $Z_i = \rho_i v_i$  respectively ( $i = 1, 2$ ). The dielectric constants of the vacuum, supported layer and substrate are  $\epsilon_0$ ,  $\epsilon_1$  and  $\epsilon_2$ , respectively. Since we are interested in longitudinal phonons propagating along the normal to the interfaces  $x_3$ , the BLS is envisaged in a backscattering geometry with both incident ( $k_i$ ) and scattered ( $k_s$ ) wavevectors forming an angle  $\alpha$  with the  $x_3$  axis. Additionally, we consider the so-called PP configuration with both, the incident electric field  $E_i$  and the scattered electric field  $E_s$ , polarized along the  $x_2$  direction (transverse electric polarization). Let us also notice that the magnitudes of the scattered and incident wavevectors are very close to each other  $k_i \approx k_s$ . Indeed, the phonon frequency is much lower than that of the light, so the incident  $\omega_i'$  and scattered  $\omega_s'$  photon frequencies are almost identical  $\omega_i' \approx \omega_s'$ .



**Figure 1.** Schematic representation of one layer (labeled  $i = 1$ ) of width  $d$  deposited on a substrate (labeled  $i = 2$ ). The  $x_3$  axis is normal to the surface.  $k_i$  and  $k_s$  are the incident and scattered wavevectors in vacuum. The electromagnetic fields are polarized along the  $x_2$  axis.  $\alpha$  and  $\theta$  are the incident and refracted angles respectively.

There are two different mechanisms contributing to the scattered light intensity, namely the photoelastic and interface motion effects. The former mechanism can be described as an acoustic modulation of the dielectric constant in the bulk of each medium by means of the photoelastic constant  $p_i$  of this medium:  $\delta\varepsilon_i = \varepsilon_i^2 p_i \frac{\partial u_i(x_3)}{\partial x_3}$  ( $p_i$  stands for the photoelastic constant  $p_{12}$  in layer  $i$  ( $i = 1, 2$ )). Then, in the presence of an incident electric field  $E_i(x_3)$ , the strain due to displacement field  $u_i(x_3)$  induces a polarization given by [57]

$$P(x_3) = \delta\varepsilon_i E_i(x_3) = \varepsilon_i^2 p_i \frac{\partial u_i(x_3)}{\partial x_3} E_i(x_3) \quad (1)$$

The contribution of the scattered electric field  $E_s^{(layer)}$  of the layer at any point  $x'_3$  is obtained by the following equation [57]

$$E_s^{(layer)}(x'_3, \omega') = \varepsilon_1^2 p_1 \int_0^d \frac{\partial u_1(x_3)}{\partial x_3} E_1(x_3) g'(x_3, x'_3, \omega') dx_3 \quad (2)$$

where  $g'(x_3, x'_3, \omega')$  is the electromagnetic Green's function between the point  $x_3$  where the polarization is located and any point  $x'_3$  where the scattered field is observed (here the vacuum medium, Figure 1), and  $\omega'$  is the electromagnetic angular frequency.

Similarly, we can calculate the contribution of the scattered field  $E_s^{(sub)}$  coming from the substrate as follows [57]

$$E_s^{(sub)}(x'_3, \omega') = \varepsilon_2^2 p_2 \int_{-L}^0 \frac{\partial u_2(x_3)}{\partial x_3} E_2(x_3) g'(x_3, x'_3, \omega') dx_3 \quad (3)$$

where  $L$  is the depth over which light is supposed to interact with phonons in the substrate.

The second mechanism, called "moving interface" or "ripple" effect, results from the difference between the dielectric constants of two adjacent media  $i$  and  $j$ , since the displacement at their interface changes the dielectric constants of a thin layer of material from  $\varepsilon_i$  to  $\varepsilon_j$  and vice versa. Consequently, it is proportional to the interface displacement in contrast to the photoelastic effect, which depends on the strain. It can be written as [57]:

$$E_s^{(ripple)}(x'_3, \omega') = (\varepsilon_0 - \varepsilon_1) u_1(d) E_1(d) g'(d, x'_3, \omega') + (\varepsilon_1 - \varepsilon_2) u_1(0) E_1(0) g'(0, x'_3, \omega') \quad (4)$$

The scattered intensity of the structure is then given as the square of the sum of all scattered electric fields  $E_s^{(layer)}$ ,  $E_s^{(sub)}$  and  $E_s^{(ripple)}$ , namely

$$I = \left| E_s^{(layer)} + E_s^{(sub)} + E_s^{(ripple)} \right|^2 \quad (5)$$

To calculate the above scattered fields (Equations (2)–(4)), we need the spatial distribution of the displacement field and the incident electric field, as well as the electromagnetic Green function  $g'(x_3, x'_3, \omega')$  of the multilayer structure. The details of these calculations are given in the Supplementary Materials. Let us notice that the expressions of the displacement field and the incident electric field are very easy to calculate and the utilization of the Green function approach in this work is mainly motivated by the knowledge that the function  $g'(x_3, x'_3, \omega')$  will later allow us to calculate the vibrational density of states.

For instance, the displacement field distribution can be obtained by launching an incident wave from the substrate (see also Supplementary Materials) and calculating its reflection at the boundaries  $x_3 = 0$  and  $x_3 = d$ . In this way, we obtain the implicit expressions of the displacement fields in the layer ( $0 \leq x_3 \leq d$ ) and substrate ( $x_3 \leq 0$ ), respectively, as follows

$$u_1(x_3) = C \left[ A(\omega) e^{-jk_1(\frac{d}{2}-x_3)} + B(\omega) e^{jk_1(\frac{d}{2}-x_3)} \right] \quad (6)$$

and

$$u_2(x_3) = C(e^{-jk_2 x_3} + r e^{+jk_2 x_3}) \quad (7)$$

where  $k_i = \omega/v_i$  is the wavevector in medium  $i$ ,  $v_i$  is the longitudinal velocity of phonons in medium  $i$  ( $i = 1, 2$ ) and  $\omega$  is their elastic angular frequency.  $C$  is the constant of integration of the displacement field and  $A(\omega)$  and  $B(\omega)$  are the amplitudes of the incident and reflected elastic waves in layer 1 containing all the information on the mechanical properties of the system. Their explicit expressions are given in Supplementary Materials. The parameter  $r$  corresponds to the acoustic reflected wave in the substrate; its expression (see Supplementary Materials) is given by

$$r = -\frac{Z_1 \sin\left(\frac{\omega d}{v_1}\right) - jZ_2 \cos\left(\frac{\omega d}{v_1}\right)}{Z_1 \sin\left(\frac{\omega d}{v_1}\right) + jZ_2 \cos\left(\frac{\omega d}{v_1}\right)} \quad (8)$$

It is worth noticing that the displacement field throughout the structure must be normalized. Indeed, the constant  $C$  in Equations (6) and (7) is obtained by the normalization condition of the displacement field throughout the system (see Supplementary Materials), namely

$$\int_{-L}^0 \omega^2 \rho_2 |u_2(x_3)|^2 dx_3 + \int_0^d \omega^2 \rho_1 |u_1(x_3)|^2 dx_3 = \left(n(\omega) + \frac{1}{2}\right) \hbar \omega \quad (9)$$

where  $n(\omega)$  is the Bose–Einstein population factor and  $\hbar$  is the reduced Planck constant ( $\hbar/2\pi$ ). It should be noted that for high temperature  $\left(n(\omega) + \frac{1}{2}\right) \hbar \omega \approx k_B T$ , where  $k_B$  is the Boltzmann constant.

Similarly, the implicit expressions of the electric fields in the layer ( $0 \leq x_3 \leq d$ ) and substrate ( $x_3 \leq 0$ ) can be written, respectively, (see Supplementary Materials) as

$$E_1(x_3) = A'(\omega') e^{-jk'_1(\frac{d}{2}-x_3)} + B'(\omega') e^{+jk'_1(\frac{d}{2}-x_3)} \quad (10)$$

$$E_2(x_3) = t' e^{-jk'_2 x_3} \quad (11)$$

where  $k'_i = \omega' n_i/c = 2\pi n_i/\lambda$  is the wavevector of the electric field in each medium ( $i = 1, 2$ ).  $\lambda$  is the wavelength of the incident light in vacuum. The amplitudes  $A'(\omega')$  and  $B'(\omega')$  of the incident and reflected electromagnetic waves in layer 1 contain all the information on the optical properties of the system. Their explicit expressions are given in Supplementary Materials.

The Green's function between any source point in the layer ( $0 \leq x_3 \leq d$ ) and the observation point in vacuum ( $x'_3 \geq d$ ) is given by (see Supplementary Materials)

$$g'(x_3, x'_3, \omega') = e^{jk'_0(x'_3-d)} \left\{ A'(\omega') e^{-jk'_1(\frac{d}{2}-x_3)} + B'(\omega') e^{+jk'_1(\frac{d}{2}-x_3)} \right\} \quad (12)$$

where  $k'_0 = \omega'/c = 2\pi/\lambda$  is the wavevector of the electric field in vacuum.

In the same way, the Green's function between any source point in the substrate ( $x_3 \leq 0$ ) and the observation point in vacuum ( $x'_3 \geq d$ ) is given by (see Supplementary Materials)

$$g'(x_3, x'_3, \omega') = \frac{-jt'}{2k'_0} e^{jk'_0(x'_3-d)} e^{-jk'_2 x_3} \quad (13)$$

By replacing Equations (6), (10) and (12) in Equation (2), we obtain

$$\begin{aligned} E_s^{(layer)}(x'_3) = \varepsilon_1^2 p_1 d e^{jk'_0(x'_3-d)} \frac{k_1 k'_1}{\sin(k_1 d) \sin(k'_1 d)^2} \left\{ [A(\omega) A'(\omega')^2 \right. \\ + B(\omega) B'(\omega')^2] \text{sinc}\left(\frac{(k_1+2k'_1)d}{2}\right) \\ - 2[A(\omega) A'(\omega') B'(\omega') + B(\omega) B'(\omega') A'(\omega')] \text{sinc}\left(\frac{k_1 d}{2}\right) \\ \left. + [A(\omega) B'(\omega')^2 + B(\omega) A'(\omega')^2] \text{sinc}\left(\frac{(k_1-2k'_1)d}{2}\right) \right\} \quad (14) \end{aligned}$$

Due to the shape of the sinc function, the three terms in the RHS of Equation (14) take significant values only around  $k_1 = \frac{\omega}{v_1} = -2k'_1 = -4\pi n_1/\lambda$  (anti-Stokes contribution),  $k_1 = \frac{\omega}{v_1} = 0$  (elastic scattering) and  $k_1 = \frac{\omega}{v_1} = 2k'_1 = 4\pi n_1/\lambda$  (Stokes contribution). We can notice that the Stokes term in Equation (14) gives a peak around the Brillouin frequency of the layer  $f_1 = 2n_1v_1/\lambda$ .

Similarly, by replacing Equations (7), (11) and (13) in Equation (3), we can calculate the contribution of the scattered field coming from the substrate as follows

$$E_s^{(sub)}(x'_3) = \varepsilon_2^2 p_2 e^{jk'_0(x'_3-d)L} \frac{k_2 k'_2 t^2}{\sin(k_2 L) \sin(k'_2 L)^2} \left\{ \text{sinc}\left(\frac{(k_2 + 2k'_2)L}{2}\right) + r \text{sinc}\left(\frac{(k_2 - 2k'_2)L}{2}\right) \right\} \quad (15)$$

where  $k_2 = \omega/v_2$ ,  $k'_2 = \omega'n_2/c = 2\pi n_2/\lambda$  and  $k'_0 = \omega'/c = 2\pi/\lambda$ . We can notice that the Stokes term in Equation (15) gives a peak around the Brillouin frequency of the substrate  $f_2 = 2n_2v_2/\lambda$ .

Finally, From Equations (6), (10) and (12), one can derive the moving interface (ripple) contribution (Equation (4)) as

$$E_s^{(ripple)}(x'_3) = C e^{jk'_0(x'_3-d)} \left\{ (\varepsilon_0 - \varepsilon_1) \left[ A(\omega) e^{jk_1 \frac{d}{2}} + B(\omega) e^{-jk_1 \frac{d}{2}} \right] \left[ A'(\omega') e^{jk_1 \frac{d}{2}} + B'(\omega') e^{-jk_1 \frac{d}{2}} \right]^2 - \frac{j}{2k'_0} (\varepsilon_1 - \varepsilon_2) (1+r) t^2 \right\} \quad (16)$$

### 2.2. Density of States and Reflection Delay Time

The density of states (DOS) of the whole system is an interesting quantity as it enables us to deduce the distribution and the weight of the different modes. In the case of the supported layer, we can calculate the variation of DOS ( $\Delta n(\omega)$ ) between the supported layer and the two constituting materials (layer and substrate) taken separately. This quantity is given by [1]

$$\Delta n(\omega) = \frac{1}{\pi} \frac{d}{d\omega} [\text{Arg}(g(0,0))] \quad (17)$$

where  $g(0,0)$  is the acoustic Green's function at the interface  $x_3 = 0$  (see Supplementary Materials). From the expression of  $g(0,0)$ , one can easily derive

$$\Delta n(\omega) = \frac{1}{\pi} \frac{Z_1 Z_2}{\left( Z_1 \sin\left(\frac{\omega d}{v_1}\right) \right)^2 + \left( Z_2 \cos\left(\frac{\omega d}{v_1}\right) \right)^2} \quad (18)$$

This variation of DOS can be related to the acoustic reflection delay time defined by

$$\tau(\omega) = \frac{d}{d\omega} [\text{Arg}(r)] \quad (19)$$

From the expression of  $r$  (Equations (8) and (18)), one can further conveniently derive an expression for the acoustic reflection delay time as

$$\tau(\omega) = \frac{2Z_1 Z_2}{\left( Z_1 \sin\left(\frac{\omega d}{v_1}\right) \right)^2 + \left( Z_2 \cos\left(\frac{\omega d}{v_1}\right) \right)^2} \quad (20)$$

Equations (18) and (20) provide the relationship between the variation of DOS and the reflection delay time  $\tau$  as:

$$\tau(\omega) = 2\pi \Delta n(\omega) \quad (21)$$

### 2.3. Particular Case of a Soft Layer on a Hard Substrate

In order to explain the behavior of the experimental BLS spectra, we have simplified the theoretical expression of the light scattered intensity of the system (layer/substrate) which is defined as the sum of both layer and substrate contributions. In order to examine each contribution, it is convenient to evaluate their amplitudes separately. However, several assumptions can be made for a soft layer on a hard substrate, i.e., (i) the main intensity

contribution comes from the surface layer as phonons are confined essentially in the top layer. (ii) The light wave in the substrate is attenuated due to imaginary parts of the complex refractive index of the substrate (see Section 3.2). (iii) The substrate contribution in the scattering intensity falls at a higher frequency far from those of the layer modes (see Section 3.2). (iv) The photoelastic constant of the substrate (here silicon) is very small in comparison with the one of the surface layer (PMMA) (see Table 1). With the above assumptions, the main contributions to the BLS intensity (Equation (5)) come from the photoelastic contribution of the layer ( $E_s^{(layer)}$ , Equation (2) or Equation (14)) and the moving interface contribution ( $E_s^{(ripple)}$ , Equation (4) or Equation (16)). We shall see below that the latter contribution only contributes non-negligibly if the layer is very thin, namely below 300 nm. Otherwise, the only remaining contribution comes from  $E_s^{(1)}$ , whose Stokes term can be written from Equation (14) as:

$$E_s^{(1)}(x'_3) \propto [A(\omega)B'(\omega')^2 + B(\omega)A'(\omega')^2] \text{sinc}\left(\frac{(k_1 - 2k'_1)d}{2}\right) e^{-k'_0(x'_3-d)} \quad (22)$$

**Table 1.** Physical quantities of the PMMA layer and Si substrate used in the theoretical calculations. Mass density ( $\rho$ ), sound velocity ( $v$ ), photoelastic constant ( $p_{12}$ ) and refractive index ( $n$ ).

Material	$\rho$ (Kg/m <sup>3</sup> )	$v$ (m/s)	$p_{12}$	$n$
PMMA	1150	2778	0.3	1.4932
Si	2335	8431	0.01	3.5 – 0.26i

From the expressions of  $A(\omega)$ ,  $B(\omega)$ ,  $A'(\omega')$  and  $B'(\omega')$  (Equations (S10), (S11), (S23) and (S24)), one can get the following simple expression

$$E_s^{(1)}(x'_3) \propto \left[ (n_1^2 + n_2^2) \sin\left(\frac{(k_1+2k'_1)d}{2}\right) - j2n_1n_2 \cos\left(\frac{(k_1+2k'_1)d}{2}\right) \right] \frac{\text{sinc}\left(\frac{(k_1-2k'_1)d}{2}\right)}{Z_2 \cos\left(\frac{\omega d}{v_1}\right) - jZ_1 \sin\left(\frac{\omega d}{v_1}\right)} e^{-k'_0(x'_3-d)} \quad (23)$$

where the main modes of the surface layer are observed around  $k_1 = 2k'_1$ . We can see that the optical modulation of the refractive index in the system will affect only the amplitude in Equation (23) through the term between brackets, which means that the main behavior of the scattering amplitude follows a sinc function. Indeed, around  $k_1 = 2k'_1$ , the intensity can be written very simply as

$$I \propto \frac{\text{sinc}^2\left(\left(\frac{\omega}{v_1} - q\right)d/2\right)}{\left(Z_2 \cos\left(\frac{\omega d}{v_1}\right)\right)^2 + \left(Z_1 \sin\left(\frac{\omega d}{v_1}\right)\right)^2} \quad (24)$$

where  $q = 2k'_1 = 4\pi n_1/\lambda$  is the analog of scattering wavevector in layer 1.

From Equations (17) and (24), one can see that the scattered intensity can be considered as a density of states modulated by the square modulus of the sinc function  $\sin^2\left(\left(\frac{\omega}{v_1} - q\right)d/2\right)$ , namely

$$I \propto \Delta n(\omega) \text{sinc}^2\left(\left(\frac{\omega}{v_1} - q\right)d/2\right) \quad (25)$$

### 3. Numerical and Experimental Results

#### 3.1. Experimental Setup

The polymer chosen for the investigation was PMMA 75K300 from MicroChem Corp. Layers with thickness ranging from 250 nm to 10  $\mu\text{m}$  were fabricated by spin-coating for 30 s with angular velocities ranging from 500 to 3000 revolutions per minute on top of a Si substrate. The spectra were taken with a multipass (3+3) Tandem Fabry–Perot



Interferometer from JRS Scientific Instruments. The  $\lambda = 514.5$  nm line of an Ar gas-ion laser was used for the incident radiation, at a mirror spacing of 6 mm and scanning amplitude of 490 nm, resulting in a free spectral range (FSR) of  $\pm 23.8$  GHz. The backscattering angle was set to 8 degrees [58]. The finite angle prevented reflected light from entering the collection objective, and subsequently the spectrometer. This angle causes an increase in the effective cavity length of  $d/\cos\theta$ . However, due to Snell's law, the angle inside the polymer is reduced to 5.3 degrees, which causes an overestimation of the thickness of the polymer layer of less than half a percent. As the polymer is assumed to be isotropic, the change in angle does not affect the acoustic velocity. The laser power was kept as small as possible to avoid any heating effect, the glass transition temperature of PMMA was taken around 110 °C, the polarization of incident and reflected beam was PP with respect to the sample plane, the crystallographic orientation of the Si substrate was (100), the resistivity or carrier concentration of the Si substrate was 11.5 ohm·cm, p doped boron and the FPI finesse for FSR = 23.8 GHz was set to 100.

### 3.2. Results and Discussion

The Brillouin spectra for the PMMA layers of different thicknesses are shown in Figure 2a by full curves. When the thickness of the film was reduced to below one micrometer, a triplet structure was observed around  $q = 0.036$  nm<sup>-1</sup> (i.e.,  $f_1 = qv_1/2\pi = 15.9$  GHz). Indeed, multiple reflections of an acoustic excitation from the film surface and interface with the substrate give rise to the equally spaced modes yielding to standing waves. Furthermore, a sufficiently large elastic impedance  $Z = \rho v$  mismatch (involving two physical quantities, density  $\rho$  and longitudinal sound velocity  $v$ ) is required for these standing waves observations and results in the quantification of their frequencies.

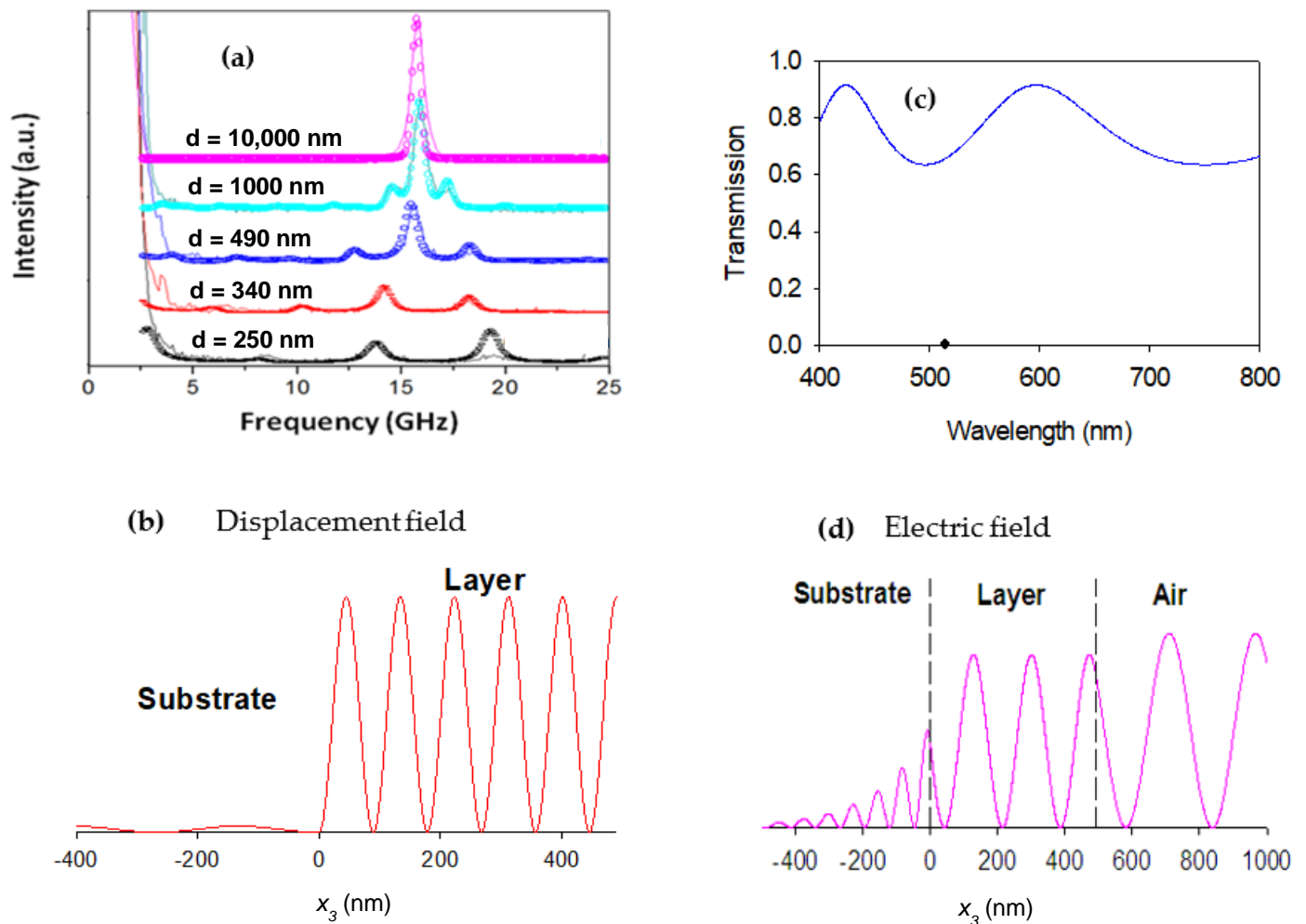
At normal incidence, the eigenmodes (standing modes) of the soft layer in contact with a hard substrate are given by  $\cos\left(\frac{\omega d}{v_1}\right) = 0$ , i.e.,  $f_m = (2m + 1)v_1/4d$  ( $m$  is an integer). One can notice that for films with further increasing thicknesses, the spacing between the equidistant longitudinal acoustic modes  $\Delta f_m = v_1/2d$  decreases, giving rise to a single mode (for thick layer  $d = 10$  μm) falling at the frequency of the longitudinal bulk-like acoustic mode in the polymer, namely  $f_1 = v_1q/2\pi \simeq 16$  GHz. Indeed, for a thick layer, the frequencies of the modes become very close to each other and the sinc function becomes a delta function, with the result that only the phonon wavevector respecting the conservation of the momentum  $q = k_i - k_s$  is observed, as illustrated in Figure 2a for  $d = 10$  μm. The intensity of the peak coming from the longitudinal bulk-like acoustic mode in the substrate falls at a high Brillouin frequency  $f_2 = 2n_2v_2/\lambda \simeq 114$  GHz, and therefore does not interfere with the spectra coming from the layer observed around 16 GHz.

We have reproduced the theoretical results corresponding to the experimental spectra in Figure 2a represented by open circles using Equations (6), (11), (14) and (15). The elastic, optic and photoelastic parameters of both PMMA and Si materials used in the theoretical calculations are listed in Table 1 [41,59,60]. Good agreement between the theoretical curves and the experimental data was found. The theoretical spectra had to be convoluted with the instrumental broadening function (Gaussian with  $\Gamma \approx 0.53$  GHz) to match the experimental spectra in Figure 2a. It is worth noticing that the contribution coming from the motion of the interfaces (Equation (14)) is negligible, especially for thick layers as it is explained in Figure A1 in the Appendix A.

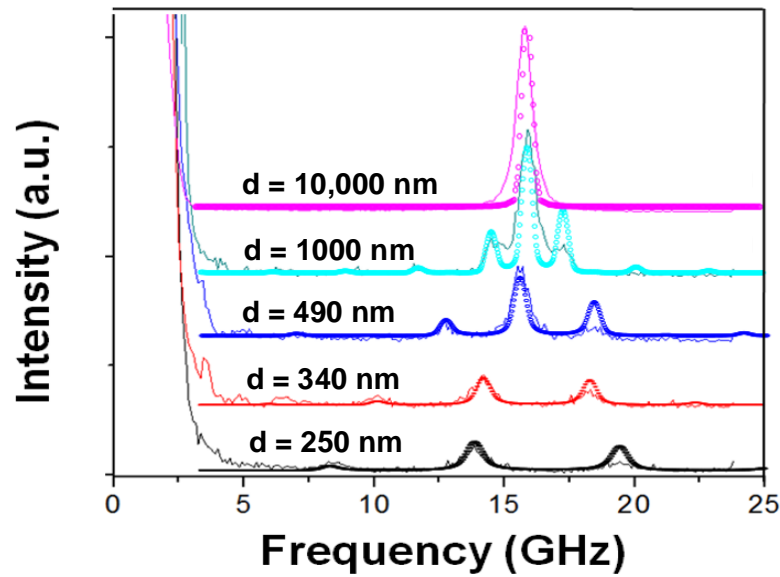
Figure 2b shows the displacement field versus the space position for the mode at  $f = 16$  GHz and  $d = 490$  nm. One can see that the elastic field is well confined to the layer and almost vanishes in the substrate. Figure 2c shows the behavior of the transmission of the optical wave as a function of the wavelength. The transmission amplitude (evaluated at the top of the substrate  $x_3 = 0$ ) shows Fabry–Perot oscillations with an amplitude of around 0.75 at  $\lambda = 514.5$  nm. The variation of the electric field in the  $x_3$  direction is plotted in Figure 2d for  $\lambda = 514.5$  nm and  $d = 490$  nm. One can notice a sharp decrease of the amplitude of the field as a function of the penetration depth which results from the absorption coefficient in Si (see Table 1). These results demonstrate the weak contribution

of the substrate to the scattered field and justify the assumptions made in deducing the simple analytical expression (Equation (25)). The length  $L$  of the substrate for which light interacts with phonons is less than  $1\ \mu\text{m}$  (Figure 2d).

Figure 3 shows the theoretical BLS spectra obtained from the approximate expression (Equation (22)). One can see a quite good agreement between the approximate results and the experimental data for each value of the layer thickness, which confirms the validity of the simple approximate expression given in Equation (23). The discrepancy between the observed and calculated BLS in Figure 3 is due to the simple analytical expression (Equation (23)) used where the contribution of the substrate in the BLS as well as the ripple mechanism are neglected.

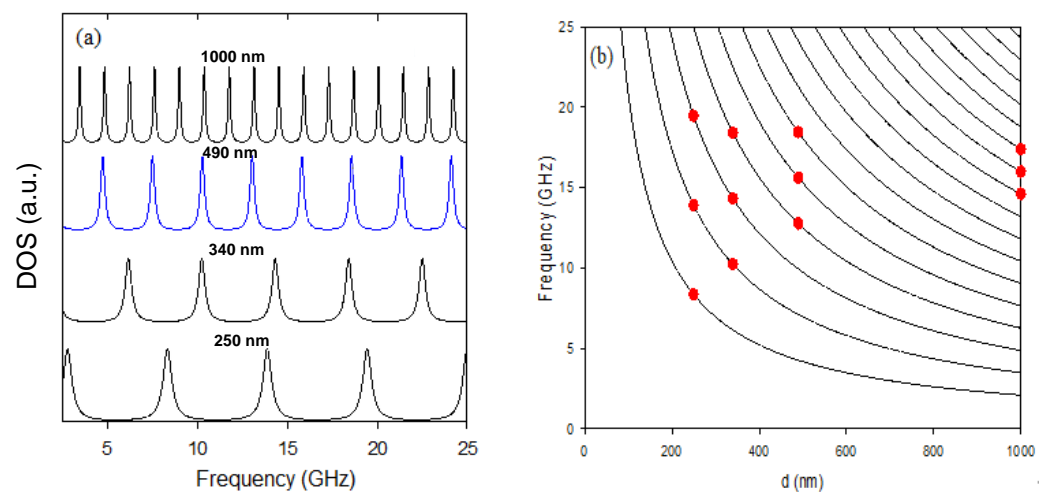


**Figure 2.** (a) Theoretical (open circles) and experimental (continuous curves) Brillouin light scattering for a series of supported PMMA films with different thicknesses deposited on a Si substrate. The main spectra appear at the frequency position of the longitudinal acoustic phonon around  $q = \frac{4\pi n_1}{\lambda} = 0.036\ \text{nm}^{-1}$  i.e.,  $f_1 = qv_1/2\pi = 15.9\ \text{GHz}$ . (b) Square modulus of the displacement field versus the space position for the mode at  $f = 16\ \text{GHz}$  and  $d = 490\ \text{nm}$ . (c) Optical transmission through the layer versus the wavelength. The circle on the abscissa axis corresponds to  $514.5\ \text{nm}$  wavelength used in the experiment. (d) Square modulus of the electric field versus the space position.



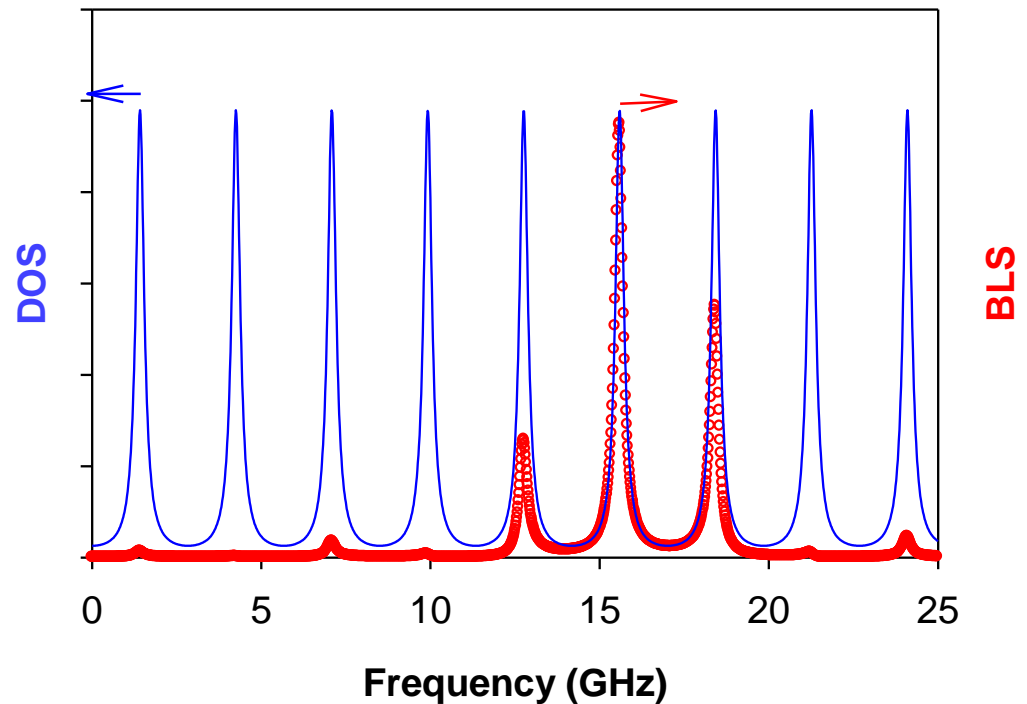
**Figure 3.** Theoretical spectra (open circles) evaluated using the approximate expression (Equation (25)) for the same thicknesses of PMMA film on Si substrate. Solid curves correspond to experiments.

The variation of the density of states (DOS) is calculated using Equation (17) for different layer thicknesses as shown in Figure 4a. As predicted from Equation (17), for  $\cos\left(\frac{\omega d}{v_1}\right) = 0$  (i.e.,  $f_m = (2m + 1)v_1/4d$ ),  $\Delta n(\omega)$  reaches a maximum value of  $\frac{1}{\pi} \frac{Z_2}{Z_1} \approx 2$  and for  $\sin\left(\frac{\omega d}{v_1}\right) = 0$  (i.e.,  $f_m = mv_1/2d$ ),  $\Delta n(\omega)$  reaches a minimum value of  $\frac{1}{\pi} \frac{Z_1}{Z_2} \approx 0.05$ . Figure 4b provides the frequencies of the layer modes (full curves) as a function of the thickness  $d$ . These modes are obtained from the maxima of the DOS displayed in Figure 4a and they coincide reasonably well with the modes obtained from the quantified expression  $f_m = (2m + 1)v_1/4d$ . One can notice a decrease of their frequencies as far as  $d$  increases. As a matter of comparison, we also reported the modes obtained from the maxima of the BLS experimental spectra around 16 GHz by red circles. We can see that the separation between the modes decreases as far as  $d$  increases. As demonstrated in Equation (21), the DOS can be extracted also from the reflection delay time, which is a measurable quantity [61]. This property has been used recently to extract the DOS from the delay time measurement in photonic coaxial cables [62].



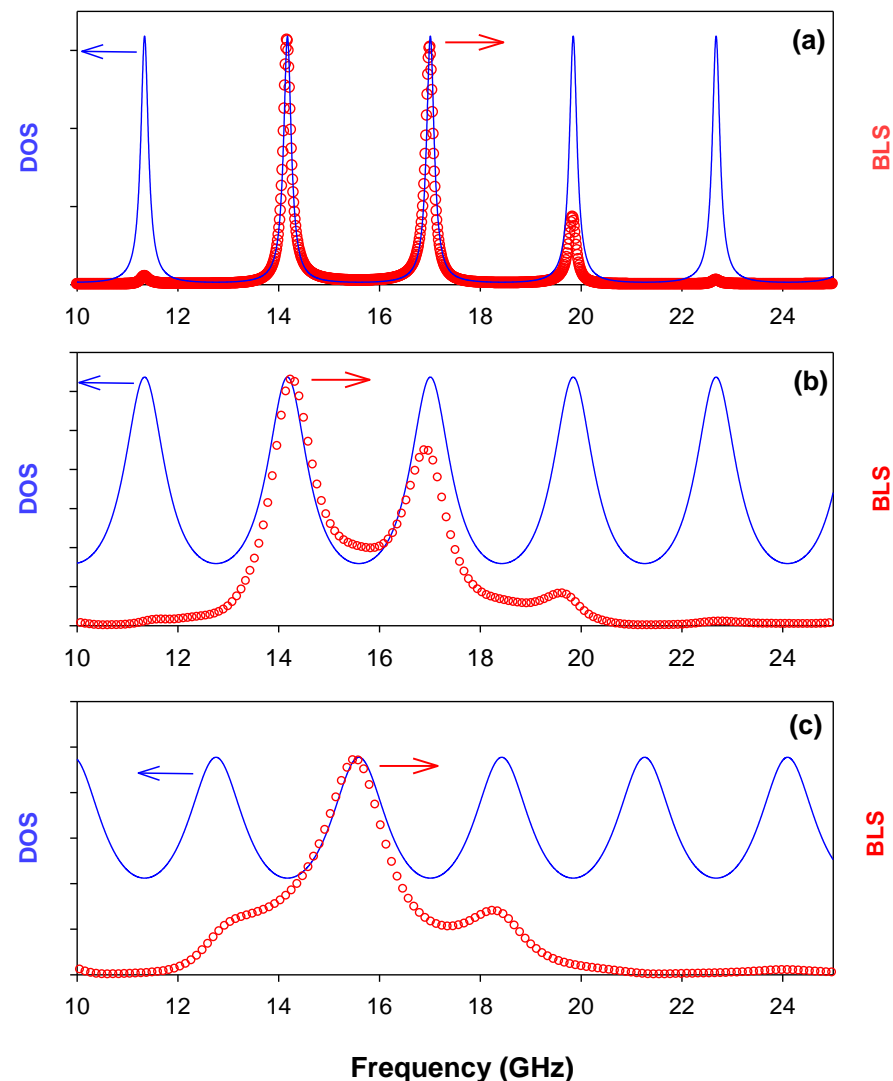
**Figure 4.** (a) Variation of density of states (in arbitrary units) of layer modes for the different layer thicknesses. (b) Quantified frequencies of layer modes as a function of layer thickness. Peak positions of experimental spectra are given as red circles around the frequency 16 GHz.

In order to give a comparison between BLS and DOS spectra, we have plotted in Figure 5 the DOS (blue curves) and the theoretical BLS spectra without convolution (red curves) for  $d = 490$  nm. One can see clearly that among all the peaks in the DOS, only those falling around 16 GHz are observed in the scattering spectrum as the latter decreases around the main peak as a sinc function. This result confirms our theoretical findings demonstrated in Equation (25).



**Figure 5.** Variation of the DOS (blue curves) and BLS intensity (red curves) as a function of the frequency for the PMMA layer of thickness  $d = 490$  nm.

As a matter of completeness, we have also numerically checked the effect of the impedance of the substrate on the shape of the DOS and the theoretical BLS spectra for the same film of thickness  $d = 490$  nm. We have found that when the impedance of the substrate  $Z_2$  is lower than that of the PMMA layer  $Z_1$  ( $Z_2 \ll Z_1$ , i.e.,  $Z_2 = 0.1Z_1$ ), then the modes of the surface layer become very close to the stationary modes of a layer with free surfaces on both sides (called an unsupported layer or membrane [17,63]). These modes are given by  $\sin\left(\frac{\omega d}{v_1}\right) = 0$  (i.e.,  $f_m = mv_1/2d$ ) as it is shown in the DOS of Figure 6a displayed by a blue curve. The behavior of the BLS (red curve) shows again a sinc function around the main peak at 17 GHz, similar to the case of the PMMA layer with a free surface from one side and a blocked surface from the other side (Figure 5). In the case where the impedance of the substrate and the surface layer are such that  $0.5Z_1 < Z_2 < 1.5Z_1$ , then oscillations in the DOS become less deep, especially for  $Z_2 \approx Z_1$ , and the behavior of the BLS spectra does not follow the shape of a sinc function as it is shown in Figure 6b,c. The reason for this discrepancy is due to the fact that the modes are not well confined in the layer and the displacement field is expanded over the substrate. Therefore, the thin layer behaves as a large layer where only the main mode around 15.5 GHz is observed as it is shown in Figure 6c. Additionally, the frequencies of the resonant modes in the DOS for  $0 \leq Z_2 < 0.5Z_1$  are close to those of the PMMA layer with free surfaces, whereas the frequencies of the resonant modes in the DOS for  $1.5Z_1 \leq Z_2$  are close to those of the PMMA layer with blocked surface from the bottom side (Figure 4a).



**Figure 6.** Same as in Figure 5 but for a hypothetical substrate with impedance  $Z_2 = 0.1 Z_1$  (a),  $Z_2 = 0.5 Z_1$  (b) and  $Z_2 = 1.5 Z_1$  (c).

#### 4. Conclusions

The results presented in this paper are based on an analytical calculation of the Brillouin light scattering and the density of states for a layer deposited on a substrate. We have presented first a detailed analytical calculation of the BLS intensity taking into account the modulation of elastic, optic and photoelastic constants in the different media constituting the system. Then, in order to explain the behavior of the experimental light scattering intensity, we have simplified the theoretical expression of the intensity of the system (layer/substrate) in the case of a soft layer on a hard substrate, which enables us to give an analytical comparison between BLS and DOS intensities. Theoretical and experimental results are given in the case of PMMA layer on Si substrate.

A very good agreement has been obtained between theoretical and experimental BLS spectra. In particular, we have shown that while the peaks in the DOS present a uniform behavior, the BLS spectra follow a sinc function shape around a given frequency fixed by the chosen laser wavelength. These results also remain valid when the impedance of the substrate is lower than that of the surface layer; however, a difference appears between DOS and BLS spectra when the impedances of the substrate and surface layer are close to each other. The results presented in this paper can be generalized to multilayered structures. This work is in progress.

**Supplementary Materials:** The following supporting information can be downloaded at: <https://www.mdpi.com/article/10.3390/cryst12091212/s1>, S1: Elastic displacement field calculation; S2: Electric field and electromagnetic Green's function calculation; S3: Determination of the constant of normalization of the displacement field. Figure S1: Schematic representation of one layer (labeled  $i = 1$ ) of width  $d$  deposited on a substrate (labeled  $i = 2$ ). The  $x_3$  axis is normal to the surface.

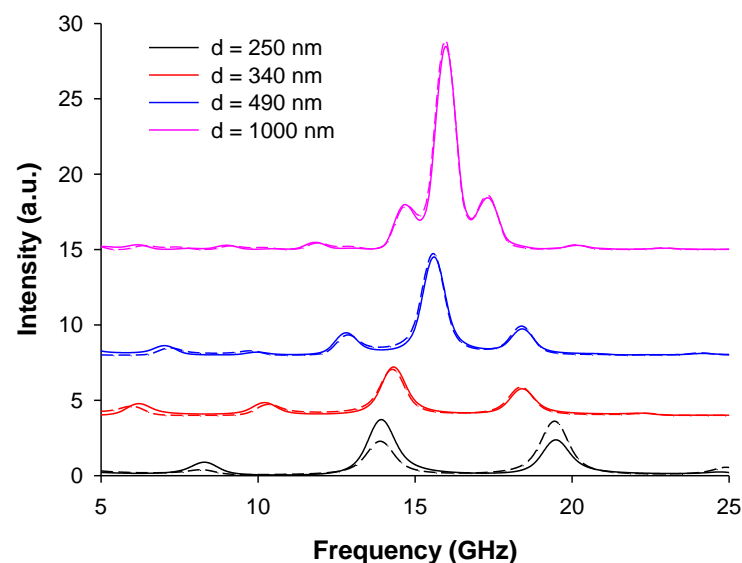
**Author Contributions:** Conceptualization, C.M.S.T. and B.D.-R.; Formal analysis, J.C., E.C.-A. and F.A.; Investigation, E.H.E.B. and B.D.-R.; Methodology, C.M.S.T.; Software, O.E.A.; Supervision, C.M.S.T. and B.D.-R.; Validation, F.A.; Visualization, E.C.-A. and F.A.; Writing—original draft, O.E.A. and J.C.; Writing—review and editing, E.H.E.B. All authors have read and agreed to the published version of the manuscript.

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### Appendix A. Effect of the Moving Interface Mechanism on BLS Spectra

In Figure A1, we give a comparison of the BLS spectra with (continuous curves) and without (dashed curves) taking into account the term associated to the moving interface or ripple effect (Equation (14)). We can see that both curves are almost similar especially for thick layers.



**Figure A1.** Theoretical Brillouin light scattering spectra displayed at  $q = 0.036 \text{ nm}^{-1}$  for a series of supported PMMA films with different thicknesses deposited on Si substrate, with (continuous curves) and without (dashed curves) taking into account the deformation of the interfaces.

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